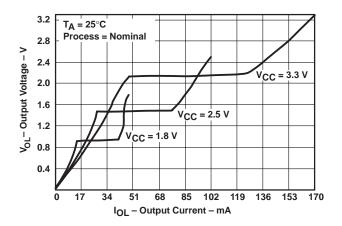
- **Member of the Texas Instruments** Widebus™ Family
- **EPIC™** (Enhanced-Performance Implanted **CMOS) Submicron Process**
- **DOC**[™] (Dynamic Output Control) Circuit **Dynamically Changes Output Impedance, Resulting in Noise Reduction Without Speed Degradation**
- **Dynamic Drive Capability Is Equivalent to** Standard Outputs With IOH and IOL of \pm 24 mA at 2.5-V V_{CC}
- Overvoltage-Tolerant Inputs/Outputs Allow **Mixed-Voltage-Mode Data Communications**

- I_{off} Supports Partial-Power-Down Mode Operation
- Ideal for Use in PC133 Registered DIMM **Applications**
- **ESD Protection Exceeds JESD 22**
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- **Package Options Include Plastic Thin** Shrink Small-Outline (DGG) and Thin Very Small-Outline (DGV) Packages

description

A Dynamic Output Control (DOC) circuit is implemented, which, during the transition, initially lowers the output impedance to effectively drive the load and, subsequently, raises the impedance to reduce noise. Figure 1 shows typical V_{OI} vs I_{OI} and V_{OH} vs I_{OH} curves to illustrate the output impedance and drive capability of the circuit. At the beginning of the signal transition, the DOC circuit provides a maximum dynamic drive that is equivalent to a high-drive standard-output device. For more information, refer to the TI application reports, AVC Logic Family Technology and Applications, literature number SCEA006, and Dynamic Output Control (DOC™) Circuitry Technology and Applications, literature number SCEA009.



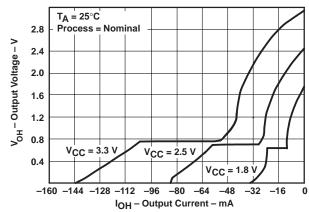


Figure 1. Output Voltage vs Output Current

This 16-bit universal bus driver is operational at 1.2-V to 3.6-V V_{CC}, but is designed specifically for 1.65-V to 3.6-V V_{CC} operation.

Data flow from A to Y is controlled by the output-enable (\overline{OE}) input. The device operates in the transparent mode when the latch-enable (\overline{LE}) input is low. When \overline{LE} is high, the A data is latched if the clock (CLK) input is held at a high or low logic level. If $\overline{\mathsf{LE}}$ is high, the A data is stored in the latch/flip-flop on the low-to-high transition of CLK. When \overline{OE} is high, the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.



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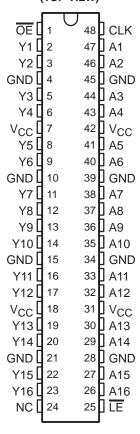
description (continued)

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The SN74AVC16334 is characterized for operation from -40°C to 85°C.

terminal assignments

DGG OR DGV PACKAGE (TOP VIEW)



NC - No internal connection

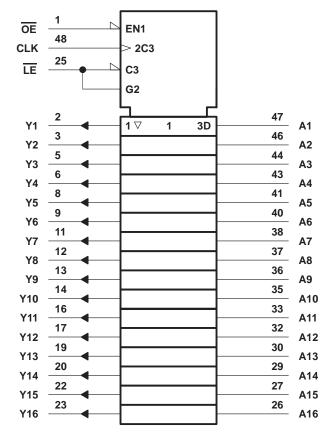
FUNCTION TABLE (each universal bus driver)

	INP	OUTPUT		
OE	LE	CLK	Α	Y
Н	Χ	Х	Χ	Z
L	L	Χ	L	L
L	L	Χ	Н	Н
L	Н	\uparrow	L	L
L	Н	\uparrow	Н	Н
L	Н	L or H	Χ	Y ₀ †

[†] Output level before the indicated steady-state input conditions were established

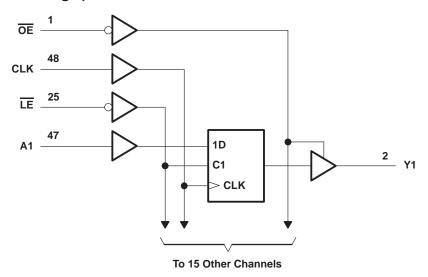


logic symbol†



[†]This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





SN74AVC16334 16-BIT UNIVERSAL BUS DRIVER WITH 3-STATE OUTPUTS

SCES154G - DECEMBER 1998 - REVISED FEBRUARY 2000

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	0.5 V to 4.6 V
Input voltage range, V _I (see Note 1)	
Voltage range applied to any output in the high-impedance or power-off state, VO	
(see Note 1)	0.5 V to 4.6 V
Voltage range applied to any output in the high or low state, VO	
(see Notes 1 and 2)	$\cdot0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I _{IK} (V _I < 0)	
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Continuous output current, IO	±50 mA
Continuous current through each V _{CC} or GND	±100 mA
Package thermal impedance, θ _{JA} (see Note 3): DGG package	70°C/W
DGV package	58°C/W
Storage temperature range, T _{stq}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
 - 2. The output positive-voltage rating may be exceeded up to 4.6 V maximum if the output current rating is observed.
 - 3. The package thermal impedance is calculated in accordance with JESD 51.



recommended operating conditions (see Note 4)

			MIN	MAX	UNIT		
\/	Cupply voltage	Operating	1.4	3.6	V		
VCC	Supply voltage	Operating	1.2		V		
		V _{CC} = 1.2 V	VCC				
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	0.65 × V _{CC}				
V_{IH}	High-level input voltage	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	0.65 × V _{CC}		V		
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7				
$V_{CC} = 1.2 \text{ V}$ $V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$ $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ $V_{CC} = 3 \text{ V to } 3.6 \text{ V}$ $V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$ $V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$ $V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$ $V_{CC} = 1.4 \text{ V to } 1.95 \text{ V}$ $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ $V_{CC} = 3 \text{ V to } 3.6 \text{ V}$ $V_{CC} = 3 \text{ V to } 3.6 \text{ V}$ $V_{CC} = 3 \text{ V to } 3.6 \text{ V}$ $V_{CC} = 3 \text{ V to } 3.6 \text{ V}$ $V_{CC} = 3 \text{ V to } 3.6 \text{ V}$ $V_{CC} = 3 \text{ V to } 3.6 \text{ V}$ $V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	2						
		V _{CC} = 1.2 V		GND			
		V _{CC} = 1.4 V to 1.6 V		0.35 × V _{CC}	1		
V_{IL}	Low-level input voltage	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		0.35 × V _{CC}	V		
		V _{CC} = 2.3 V to 2.7 V		0.7			
		V _{CC} = 3 V to 3.6 V		0.8	1		
٧ _I	Input voltage		0	3.6	V		
\/-	Output valtage	Active state	0	Vcc	V		
۷O	Output voltage	3-state	0	3.6	l ^v		
		V _{CC} = 1.4 V to 1.6 V		-2			
1	Charlie himb lavel autout aumant	V _{CC} = 1.65 V to 1.95 V		-4			
IOHS	Static nign-level output current	V _{CC} = 2.3 V to 2.7 V		-8	mA		
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		-12	1		
		V _{CC} = 1.4 V to 1.6 V		2			
1	Charles lave laved autout aurona 4 [†]	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		4			
IOLS	Static low-level output current†	V _{CC} = 2.3 V to 2.7 V		8	mA		
		V _{CC} = 3 V to 3.6 V		12	1		
Δt/Δν	Input transition rise or fall rate	V _{CC} = 1.4 V to 3.6 V		5	ns/V		
TA	Operating free-air temperature	-	-40	85	°C		

[†] Dynamic drive capability is equivalent to standard outputs with I_{OH} and I_{OL} of ±24 mA at 2.5-V V_{CC}. See Figure 1 for V_{OL} vs I_{OL} and V_{OH} vs I_{OH} characteristics. Refer to the TI application reports, *AVC Logic Family Technology and Applications*, literature number **SCEA006**, and *Dynamic Output Control (DOC™) Circuitry Technology and Applications*, literature number **SCEA009**.

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{CC}	MIN TYPT	MAX	UNIT	
		I _{OHS} = -100 μA	1.4 V to 3.6 V	V _{CC} -0.2			
		$I_{OHS} = -2 \text{ mA}, \qquad V_{IH} = 0.91 \text{ V}$	1.4 V	1.05			
Vон		$I_{OHS} = -4 \text{ mA}, \qquad V_{IH} = 1.07 \text{ V}$	1.65 V	1.2		V	
		$I_{OHS} = -8 \text{ mA}, \qquad V_{IH} = 1.7 \text{ V}$	2.3 V	1.75			
		$I_{OHS} = -12 \text{ mA}, \qquad V_{IH} = 2 \text{ V}$	3 V	2.3			
		I _{OLS} = 100 μA	1.4 V to 3.6 V		0.2		
		$I_{OLS} = 2 \text{ mA},$ $V_{IL} = 0.49 \text{ V}$	1.4 V		0.4		
VOL		$I_{OLS} = 4 \text{ mA}, \qquad V_{IL} = 0.57 \text{ V}$	1.65 V		0.45	V	
		$I_{OLS} = 8 \text{ mA}, \qquad V_{IL} = 0.7 \text{ V}$	2.3 V		0.55		
		$I_{OLS} = 12 \text{ mA}, \qquad V_{IL} = 0.8 \text{ V}$	3 V		0.7		
Ц	Control inputs	$V_I = V_{CC}$ or GND	3.6 V		±2.5	μΑ	
l _{off}		V_I or $V_O = 3.6 V$	0		±10	μΑ	
loz		$V_O = V_{CC}$ or GND	3.6 V		±10	μΑ	
ICC		$V_I = V_{CC}$ or GND, $I_O = 0$	3.6 V		40	μΑ	
	CLK input	VI – Vo a or CND	2.5 V	4			
	CLK IIIput	$V_I = V_{CC}$ or GND	3.3 V	4			
C.	Control inputs	V ₁ = V ₂ a or CND	2.5 V	4			
Ci	Control inputs	$V_I = V_{CC}$ or GND	3.3 V	4		pF	
	Data inputa	V. Vaaar CND	2.5 V	2.5			
	Data inputs	$V_I = V_{CC}$ or GND	3.3 V	2.5			
	Outputo	Va Vaaar CND	2.5 V	6.5			
Co	Outputs	$V_O = V_{CC}$ or GND	3.3 V	6.5		pF	

[†] Typical values are measured at $T_A = 25$ °C.

timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figures 2 through 5)

				V _{CC} = 1.2 V		V _{CC} = 1.5 V ± 0.1 V		V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 3.3 V ± 0.3 V		UNIT
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
fclock	Clock freq	luency							150		150		150	MHz
	Pulse LE low							3.3		3.3		3.3		no
t _W	duration	CLK high or low						3.3		3.3		3.3		ns
		Data before CLK↑		1		0.8		0.7		0.7		0.7		
t _{su}	Setup time	Data	CLK high	1.5		1.4		0.9		0.9		0.9		ns
	uno	before LE↑	CLK low	2.7		1.6		1.2		1		1		
t _h	Hold time	Data after CLK↑		1.3		1.1		0.9		0.8		0.7		ns
4.	Hold	Data	CLK high	2.2		1.9		1.7		1.5		1.5		ns
^t h	time	after LE↑	CLK low	2.4		1.8		1.6		1.4		1.3		ns



switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 2 through 5)

PARAMETER	FROM TO (OUTPUT)		$V_{CC} = 1.2 \text{ V}$ $V_{CC} = 1.5 \pm 0.1 \text{ V}$			V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 3.3 V ± 0.3 V		UNIT
	(INPOT)	(001701)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max}						150		150		150		MHz
	А		5.3	1.2	6.2	1.5	4.9	1	3.2	0.9	2.5	
t _{pd}	LE	Υ	7	2.2	9.7	1.8	7.5	1.5	4.9	0.8	4	ns
	CLK		6	1.9	7.8	1.6	6	1.1	3.7	1	3.1	
t _{en}	ŌĒ	Υ	7.9	2.4	10.2	1.6	8.8	1.5	6.7	1	6.2	ns
t _{dis}	OE	Y	7.7	2.1	10.3	1.5	8.4	1.2	5.3	1	5.3	ns

switching characteristics, $T_A = 0$ °C to 85°C, $C_L = 0$ pF[†]

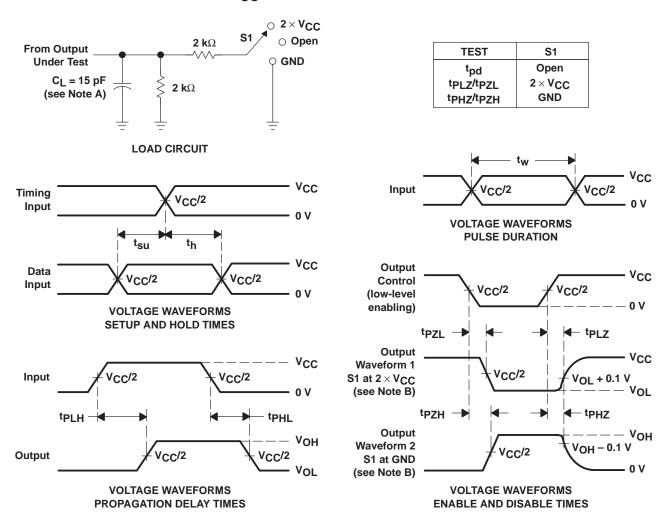
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = ± 0.1	UNIT	
	(1141 01)	(0011 01)	MIN	MAX	
^t pd	A	V	0.6	1.3	
	CLK	Ť	0.7	1.5	ns

[†] Texas Instruments SPICE simulation data

operating characteristics, T_A = 25°C

PARAMETER			TEST C	ONDITIONS	V _{CC} = 1.8 V	V _{CC} = 2.5 V	V _{CC} = 3.3 V	UNIT	
PARAMETER		TEST CONDITIONS		TYP	TYP	TYP	UNIT		
	Power dissipation	Outputs enabled	C. 0	f 40 MH I=	45	48	52	~F	
C _{pd}	capacitance	Outputs disabled	$C_L = 0$,	f = 10 MHz	23	25	28	pF	

PARAMETER MEASUREMENT INFORMATION V_{CC} = 1.2 V AND 1.5 V \pm 0.1 V



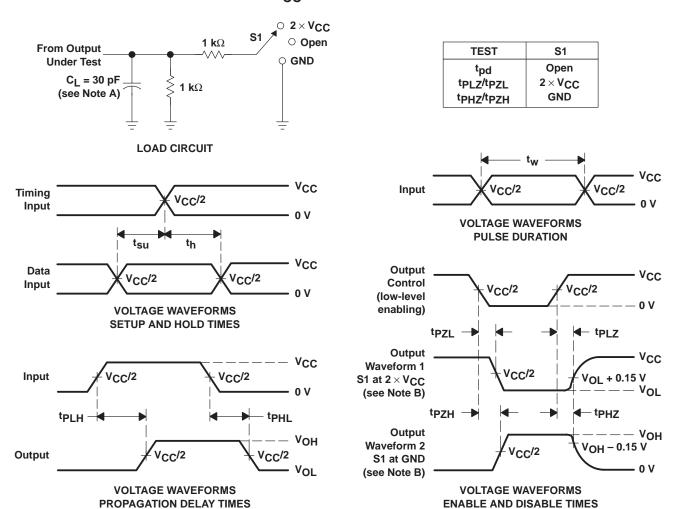
NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_Q = 50 \Omega$, $t_f \leq$ 2 ns, $t_f \leq$ 2 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLZ and tpHZ are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 2. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$

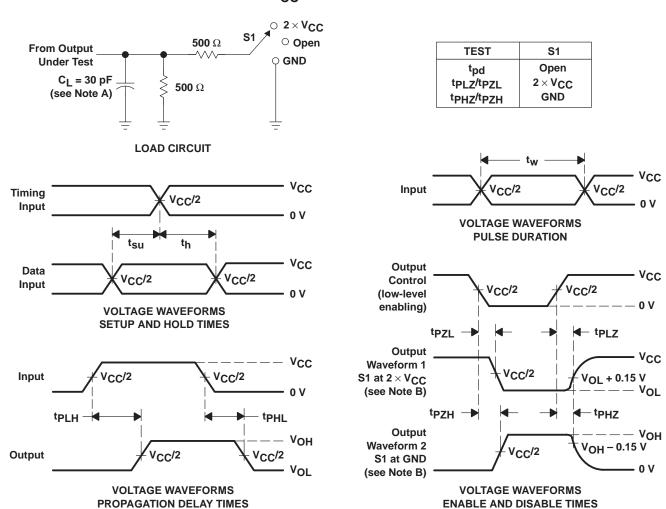


NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq 2$ ns, $t_f \leq 2$ ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLZ and tpHZ are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 3. Load Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$

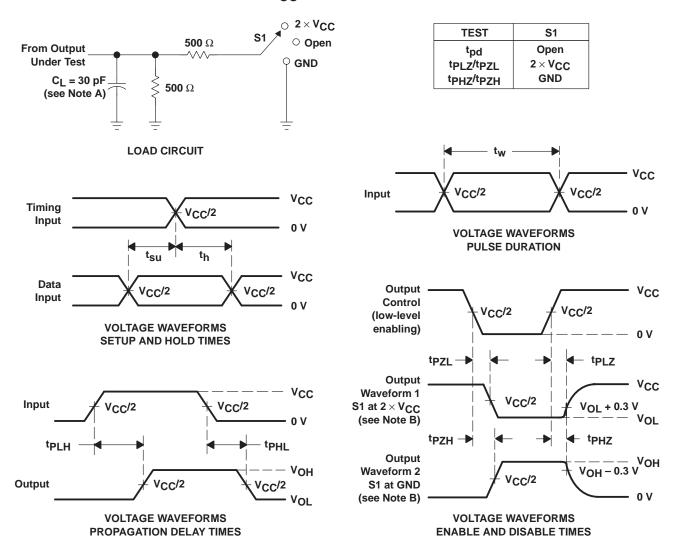


- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_Q = 50~\Omega$, $t_f \leq$ 2 ns, $t_f \leq$ 2 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tpLz and tpHz are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 4. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION V_{CC} = 3.3 V \pm 0.3 V



- NOTES: A. C_I includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq 2$ ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tpl 7 and tpH7 are the same as tdis.
 - F. t_{PZL} and t_{PZH} are the same as t_{en}.
 - G. tpLH and tpHL are the same as tpd.

Figure 5. Load Circuit and Voltage Waveforms



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